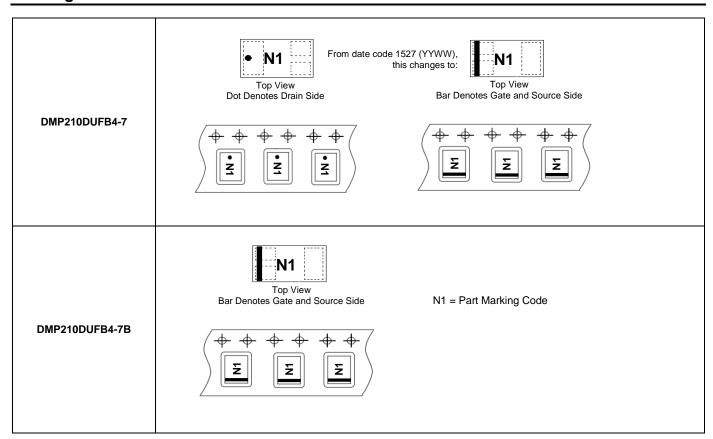


Marking Information





Maximum Ratings (@ $T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage			V _{DSS}	-20	V
Gate-Source Voltage			V _{GSS}	±10	V
Continuous Drain Current (Note 5) V _{GS} = -4.5V	Steady State	T _A = +25°C T _A = +70°C	ID	-200 -160	mA
Continuous Drain Current (Note 5) V _{GS} = -1.8V	Steady State	T _A = +25°C T _A = +70°C	ID	-140 -110	mA
Pulsed Drain Current	t _P = 10μs		I _{DM}	-600	mA

Thermal Characteristics

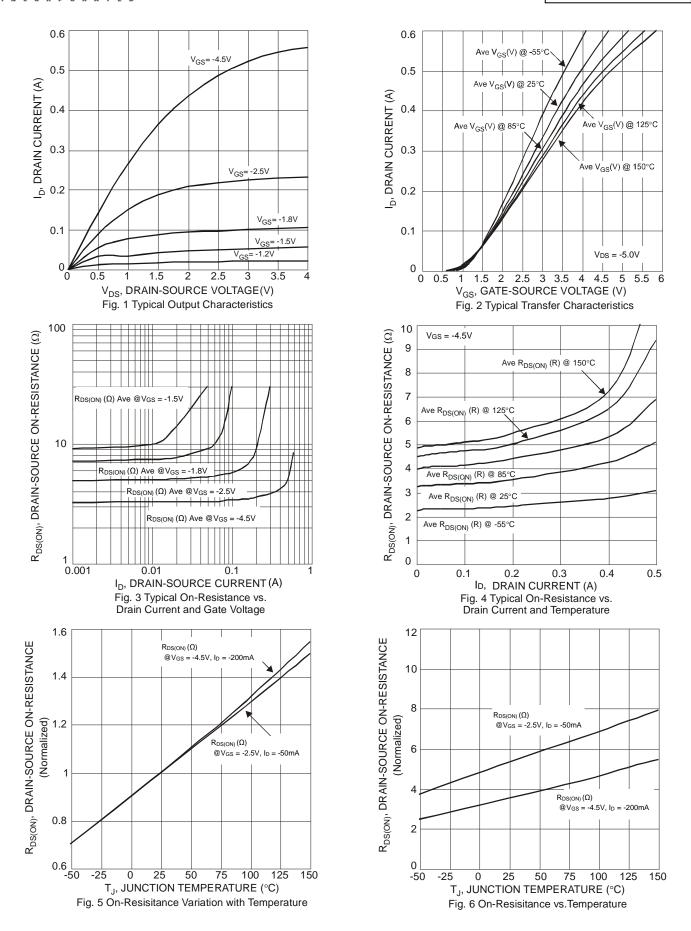
Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 5)	P _D	350	mW
Thermal Resistance, Junction to Ambient (Note 5)	Reja	357	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C

Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic		Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 6)			IVIIII	тур	IVIAX	Onit	Test Condition	
Drain-Source Breakdown Voltage		BVpss	-20	_	_	V	V _G S = 0V, I _D = -250µA	
Ţ.		D V D 00		_	-100	nA	V _{DS} = -16V, V _{GS} = 0V	
Zero Gate Voltage Drain Current		IDSS	_	_	-50	nA	V _{DS} = -5.0V, V _{GS} = 0V	
					±100	nA	$V_{GS} = \pm 5.0V, V_{DS} = 0V$	
Gate-Source Leakage		Igss	_	_	±1	μΑ	$V_{GS} = \pm 8.0 V, V_{DS} = 0 V$	
					±10	μA	$V_{GS} = \pm 10.0 V, V_{DS} = 0 V$	
ON CHARACTERISTICS (Note 6)	ON CHARACTERISTICS (Note 6)							
Gate Threshold Voltage	@T _J = +25°C	Vgs(TH)	-0.5		-1.0	V	$V_{DS} = V_{GS}$, $I_D = -250\mu A$	
Gate Threshold Voltage (Note 7)	$@T_J = 0^{\circ}C$		-0.55	_	-1.05			
	$@T_J = +85^{\circ}C$	Vgs(TH)	-0.40		-0.90	V	$V_{DS} = V_{GS}$, $I_D = -250\mu A$	
	@T _J = +100°C		-0.35		-0.85			
					5		$V_{GS} = -4.5V, I_D = -100mA$	
		RDS(ON)			7	1	$V_{GS} = -2.5V, I_{D} = -50mA$	
Static Drain-Source On-Resistance					10		$V_{GS} = -1.8V, I_{D} = -20mA$	
			_	_	15		$V_{GS} = -1.5V, I_D = -10mA$	
			_	20	_		V _G S = -1.2V, I _D = -1mA	
Forward Transfer Admittance	orward Transfer Admittance		_	200	_	mS	V _{DS} = -10V, I _D = -200mA	
Diode Forward Voltage (Note 5)		VsD	-0.5	_	-1.2	V	V _G S = 0V, I _S = -115mA	
DYNAMIC CHARACTERISTICS (Not	te 7)							
Input Capacitance	Input Capacitance			13.72	175	pF	45)/)/	
Output Capacitance Reverse Transfer Capacitance		Coss		4.01	30	pF	V _{DS} = -15V, V _{GS} = 0V -f = 1.0MHz	
		Crss		2.34	20	pF	1 - 1.0001112	
SWITCHING CHARACTERISTICS ()	Note 7)							
Turn-On Delay Time		td(on)	_	7.7	—			
Rise Time		tr	_	19.3	_	ns	$V_{GS} = -4.5V, V_{DD} = -15V$ $I_{D} = -180mA, R_{G} = 2.0\Omega$	
Turn-Off Delay Time		tD(OFF)		25.9	_	113		
all Time		tF		31.5	_			

5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.6. Short duration pulse test used to minimize self-heating effect.7. Guaranteed by design. Not subject to production testing. Notes:







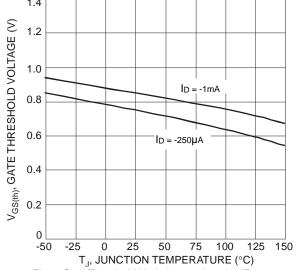
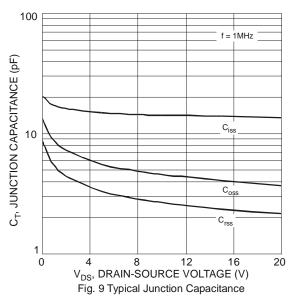
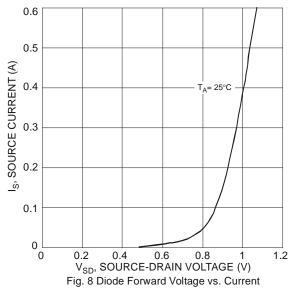


Fig. 7 Gate Threshold Variation vs. Junction Temperature





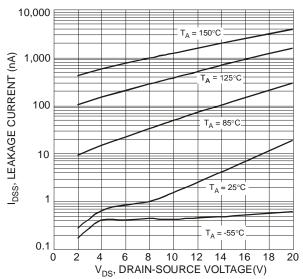


Fig. 10 Typical Drain-Source Leakage Current vs. Voltage

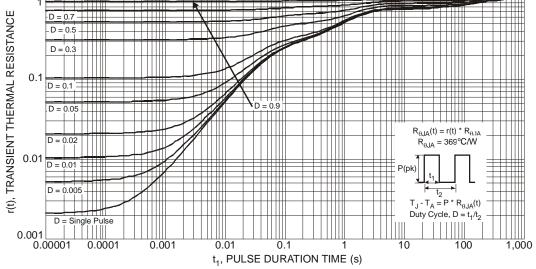


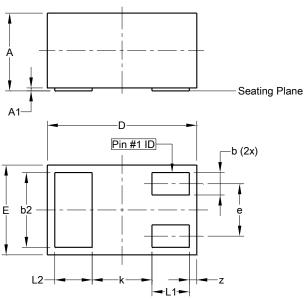
Fig. 11 Transient Thermal Response



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

X2-DFN1006-3

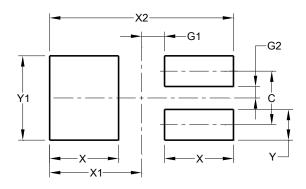


X2-DFN1006-3					
Dim	Min	Max	Тур		
Α		0.40	_		
A1	0.00	0.05	0.03		
b	0.10	0.20	0.15		
b2	0.45	0.55	0.50		
D	0.95	1.05	1.00		
Е	0.55	0.65	0.60		
е		_	0.35		
L1	0.20	0.30	0.25		
L2	0.20	0.30	0.25		
k			0.40		
Z	0.02	0.08	0.05		
All Dimensions in mm					

Suggested Pad Layout

 $\label{prop:lease} Please see \ http://www.diodes.com/package-outlines.html for the latest version.$

X2-DFN1006-3



Dimensions	Value (in mm)
С	0.350
G1	0.150
G2	0.075
X	0.450
X1	0.600
X2	1.200
Y	0.200
Y1	0.550



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7 of 7

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